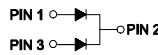
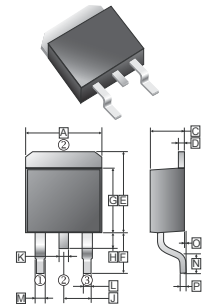


RoHS Compliant Product
 A suffix of "-C" specifies halogen & lead-free

FEATURES

- Low forward voltage drop
- High current capability
- High reliability
- High surge current capability
- Epitaxial construction

TO-263(D²-PACK)



MECHANICAL DATA

- Case: Molded plastic
- Epoxy: UL94V-0 rate flame retardant
- Lead: Lead solderable per MIL-STD-202 method 208 guaranteed
- Polarity: As Marked
- Mounting position: Any
- Weight: 2.24 grams

REF.	Millimeter		REF.	Millimeter	
	Min.	Max.		Min.	Max.
A	9.50	10.50	H	1.50	REF.
C	4.30	4.80	J	2.54	TYP.
D	1.17	1.45	K	-	-
E	9.50	10.50	L	0.71	1.00
F	4.33	5.93	M	1.17	1.47
G	8.50	9.00	P	0.31	0.53

MAXIMUM RATINGS

Rating 25°C ambient temperature unless otherwise specified.
 Single phase half wave, 60Hz, resistive or inductive load.
 For capacitive load, de-rate current by 20%.

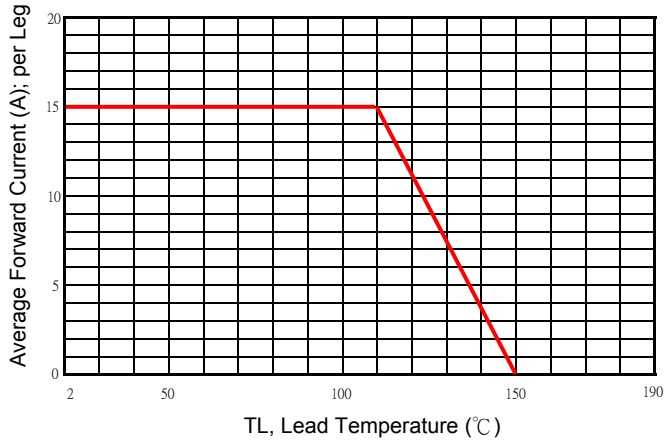
PARAMETER	SYMBOL	RATING	UNIT
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	200	V
Maximum RMS Voltage	V_{RMS}	140	V
Maximum DC Blocking Voltage	V_{DC}	200	V
Maximum Average Forward Rectified Current	I_F	30	A
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load	I_{FSM}	200	A
Maximum Instantaneous Forward Voltage @ 15A Per Diode	V_F	0.90	V
Maximum Reverse Current at Rated V_{RRM} Per Diode (Note 3)	$T_A=25^{\circ}C$	0.1	mA
	$T_A=100^{\circ}C$	5	
Typical Junction Capacitance (Note 1)	C_J	220	pF
Voltage Rate Of Change	dv/dt	10000	V/us
Typical Thermal Resistance	$R_{\theta JA}$	50	°C/W
	$R_{\theta JL}$	3.0	°C/W
Operating & Storage Temperature	T_J, T_{STG}	-55~150	°C

NOTES:

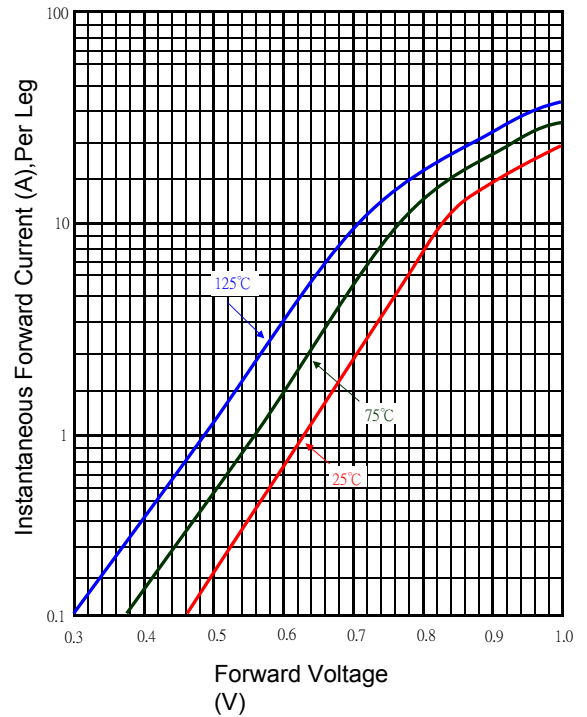
1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
2. Thermal Resistance Junction to Lead.
3. Plus test: 300uS Pulse width, 1% duty cycle..

RATINGS AND CHARACTERISTIC CURVES

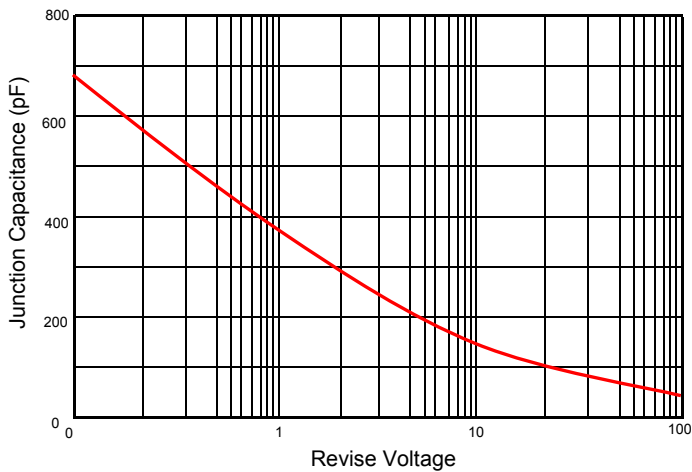
Typical Forward Current Derating Curve



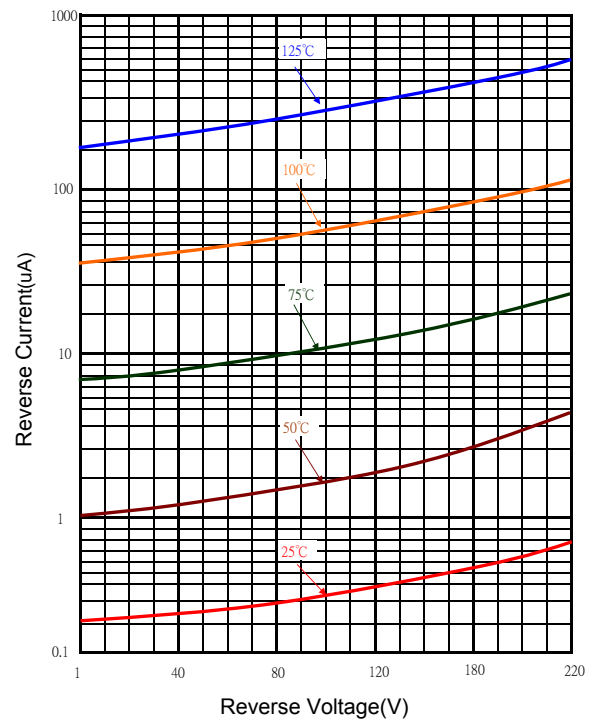
Typical Forward Characteristic



Typical Junction Capacitance



Typical Reverse Characteristic



Maximum Non- Repetitive Forward Surge Current

